NSN 5961-01-263-3511

Diode Semiconductor Device - Page 1 of 1



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Overall Length:
Between 2.180 inches and 2.390 inches
Mounting Method:
Terminal and threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
Between 1.052 inches and 1.063 inches
Thready Qty Per Inch (tpi):
24
Thread Size:
0.375 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
800.0 repetitive peak reverse voltage and 950.0 nonrepetitive peak reverse voltage and 800.0 reverse voltage, dc
Current Rating Per Characteristic:
20.00 milliamperes collector current, dc nanoamperes
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius ambient air
Thread Series Designator:
Unf
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0